

10A Avg.

400 Volts

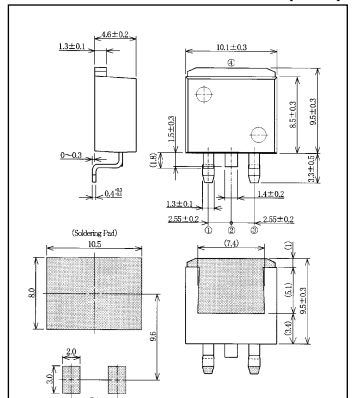
FRD

C10T40F

■最大定格 Maximum Ratings

Item	Symbol	Conditions	Unit
くり返しピーク逆電圧 Repetitive Peak Reverse Voltage	$V_{RRM}$	400	V
非くり返しピーク逆電圧 Non-repetitive Peak Reverse Voltage	$V_{RSM}$	440	V
平均整流電流 Average Rectified Forward Current	$I_O$	50Hz、正弦全波通電抵抗負荷 50Hz Full Sine Wave Resistive Load	$T_c=112^\circ\text{C}$ 10
実効順電流 R.M.S. Forward Current	$I_F(\text{RMS})$	11.1	A
サージ順電流 Surge Forward Current	$I_{FSM}$	80 50Hz正弦全波、1サイクル、非くり返し 50Hz Full Sine Wave, 1cycle, Non-repetitive	A
動作接合温度範囲 Operating Junction Temperature Range	$T_{jw}$	-40~+150	$^\circ\text{C}$
保存温度範囲 Storage Temperature Range	$T_{stg}$	-40~+150	$^\circ\text{C}$

■OUTLINE DRAWING(mm)



■APPROX. NET WEIGHT:1.4g

■電氣的・熱的特性 Electrical/Thermal Characteristics

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
ピーク逆電流 Peak Reverse Current	$I_{RM}$	$T_j=25^\circ\text{C}$ , $V_{RM}=V_{RRM}$ , 一素子あたり Per Diode	—	—	30	$\mu\text{A}$
ピーク順電圧 Peak Forward Voltage	$V_{FM}$	$T_j=25^\circ\text{C}$ , $I_{FM}=5\text{A}$ , 一素子あたり Per Diode	—	—	1.25	V
逆回復時間 Reverse Recovery Time	$t_{rr}$	$I_{FM}=5\text{A}$ , $-di/dt=50\text{A}/\mu\text{s}$ , $T_j=25^\circ\text{C}$	—	—	45	ns
熱抵抗 Thermal Resistance	$R_{th(j-c)}$	接合部・ケース間 Junction to Case	—	—	3	$^\circ\text{C}/\text{W}$

■定格・特性曲線

FIG.1

順電圧特性  
FORWARD CURRENT VS. VOLTAGE

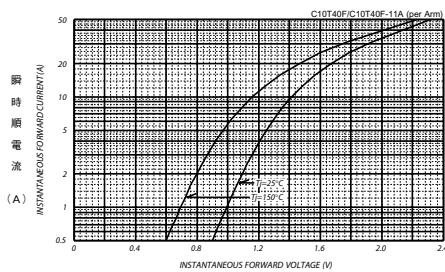


FIG.2

平均順電力損失特性  
AVERAGE FORWARD POWER DISSIPATION

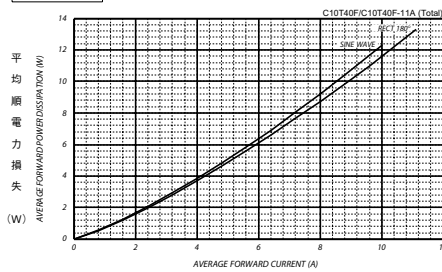


FIG.3

平均順電流-ケース温度定格  
AVERAGE FORWARD CURRENT VS. CASE TEMPERATURE

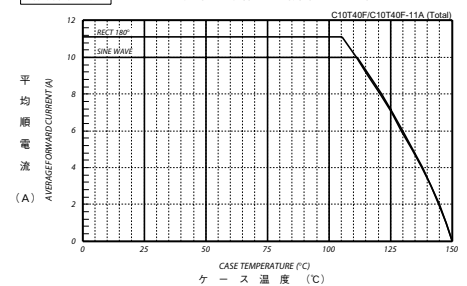


FIG.4

サージ順電流定格  
SURGE CURRENT RATINGS

